

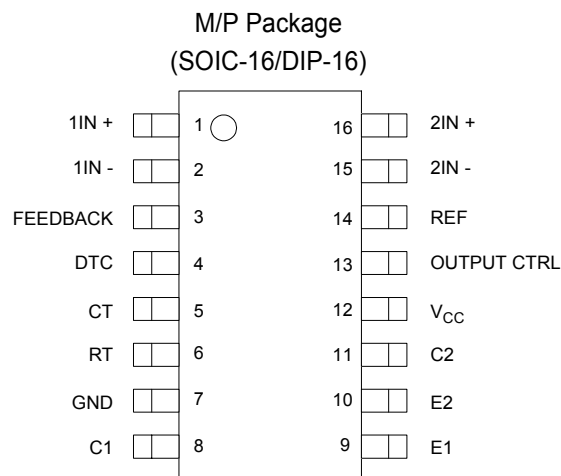
**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ494A/C****Pin Configuration**

Figure 2. Pin Configuration of AZ494A/C (Top View)

Output Function Control Table

Signal for Output Control	Output Function
$V_I = \text{GND}$	Single-ended or parallel output
$V_I = V_{\text{REF}}$	Normal push-pull operation

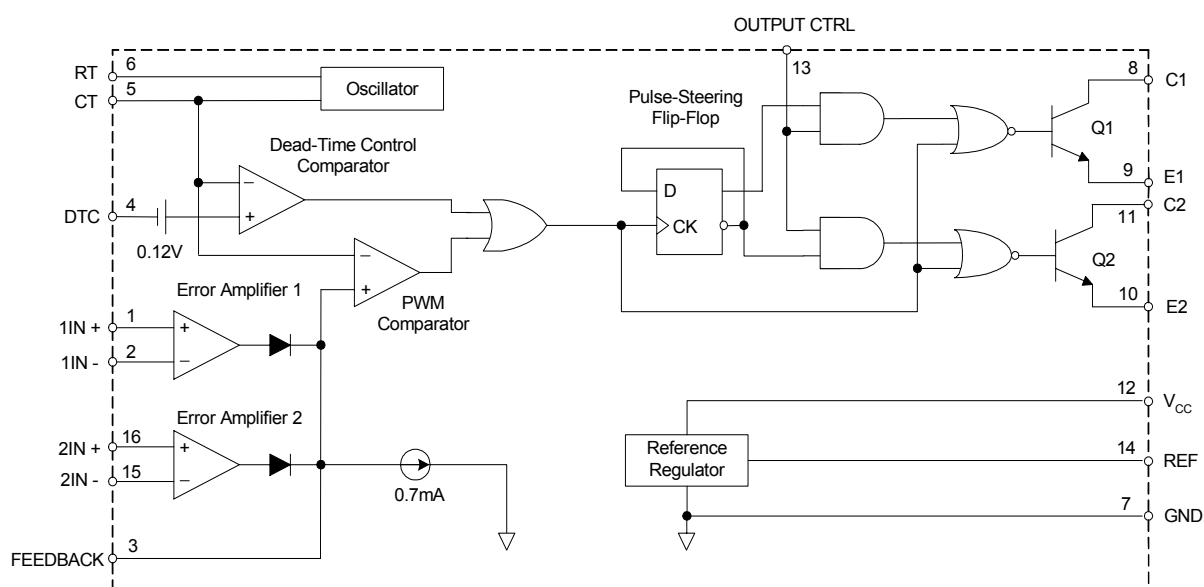
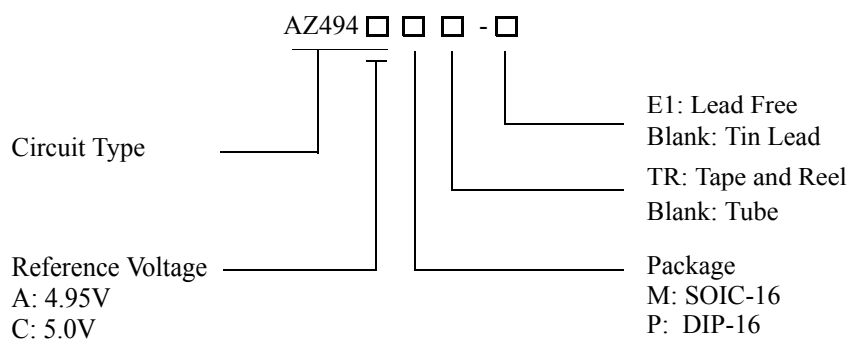
Functional Block Diagram

Figure 3. Functional Block Diagram of AZ494A/C

**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ494A/C****Ordering Information**

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Tin Lead	Lead Free	Tin Lead	Lead Free	
SOIC-16	-40 to 85°C	AZ494AM	AZ494AM-E1	AZ494AM	AZ494AM-E1	Tube
		AZ494AMTR	AZ494AMTR-E1	AZ494AM	AZ494AM-E1	Tape & Reel
		AZ494CM	AZ494CM-E1	AZ494CM	AZ494CM-E1	Tube
		AZ494CMTR	AZ494CMTR-E1	AZ494CM	AZ494CM-E1	Tape & Reel
DIP-16	-40 to 85°C	AZ494AP	AZ494AP-E1	AZ494AP	AZ494AP-E1	Tube
		AZ494CP	AZ494CP-E1	AZ494CP	AZ494CP-E1	Tube

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ494A/C****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Supply Voltage (Note 2)	V_{CC}	40		V
Amplifier Input Voltage	V_I	-0.3 to $V_{CC} + 0.3$		V
Collector Output Voltage	V_O	40		V
Collector Output Current	I_O	250		mA
Package Thermal Impedance (Note 3)	$R_{\theta JA}$	M Package	73	$^{\circ}\text{C/W}$
		P Package	67	
Lead Temperature 1.6mm from case for 10 seconds		260		$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to 150		$^{\circ}\text{C}$
ESD rating (Machine Model)		200		V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Note 2: All voltage values are with respect to the network ground terminal.

Note 3: Maximum power dissipation is a function of $T_J(\text{max})$, $R_{\theta JA}$ and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A) / R_{\theta JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	7	15	36	V
Collector Output Voltage	V_{C1}, V_{C2}		30	36	V
Collector Output Current (Each Transistor)	I_{C1}, I_{C2}			200	mA
Amplifier Input Voltage	V_I	0.3		$V_{CC} - 2$	V
Current Into Feedback Terminal	I_{FB}			0.3	mA
Reference Output Current	I_{REF}			10	mA
Timing Capacitor	C_T	0.00047	0.001	10	μF
Timing Resistor	R_T	1.8	30	500	$\text{K}\Omega$
Oscillator Frequency	f_{osc}	1.0	40	200	KHz
PWM Input Voltage (Pin 3, 4, 14)		0.3		5.3	V
Operating Free-Air Temperature	T_A	-40		85	$^{\circ}\text{C}$

**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ494A/C****Electrical Characteristics** $T_A = 25^{\circ}\text{C}$, $V_{CC}=20\text{V}$, $f=10\text{KHz}$ unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reference Section						
Output Reference Voltage for AZ494A	V _{REF}	I _{REF} =1mA	4.90	4.95	5.0	V
		I _{REF} =1mA, T _A = -40 to 85°C	4.85	4.95	5.05	V
Output Reference Voltage for AZ494C	V _{REF}	I _{REF} =1mA	4.95	5.0	5.05	V
		I _{REF} =1mA, T _A = -40 to 85°C	4.9	5.0	5.1	V
Line Regulation	R _{LINE}	V _{CC} = 7V to 36V		2	25	mV
Load Regulation	R _{LOAD}	I _{REF} =1mA to 10mA		1	15	mV
Short-Circuit Output Current	I _{SC}	V _{REF} = 0V	10	35	50	mA
Oscillator Section						
Oscillator Frequency	f _{OSC}	C _T =0.001μF, R _T =30KΩ		40		KHz
		C _T =0.01μF, R _T =12KΩ	9.2	10	10.8	
		C _T =0.01μF, R _T =12KΩ, T _A = -40 to 85°C	9.0		12	
Frequency Change with Temperature	Δf /ΔT	C _T =0.01μF, R _T =12KΩ, T _A = -40 to 85°C			1	%
Dead-Time Control Section						
Input Bias Current	I _{BIAS}	V _{CC} =15V, V4= 0 to 5.25V		-2	-10	μA
Maximum Duty Cycle	D(MAX)	V _{CC} =15V, V4= 0V, Pin 13= V _{REF}	45			%
Input Threshold Voltage	V _{ITH}	Zero Duty Cycle		3	3.3	V
		Maximum Duty Cycle	0			
Error-Amplifier Section						
Input Offset Voltage	V _{IO}	V3 = 2.5V		2	10	mV
Input Offset Current	I _{IO}	V3 = 2.5V		25	250	nA
Input Bias Current	I _{BIAS}	V3 = 2.5V		0.2	1	μA
Common-Mode Input Voltage Range	V _{CM}	V _{CC} =7V to 36V	-0.3		V _{CC} -2	V
Open-Loop Voltage Gain	G _{VO}	V _O =0.5V to 3.5V	70	95		dB
Unity-Gain Bandwidth	BW			650		KHz
Common-Mode Rejection Ratio	CMRR		65	80		dB
Output Sink Current (Feedback)	I _{SINK}	V _{ID} = -15mV to -5V, V3 = 0.7V	-0.3	-0.7		mA
Output Source Current (Feedback)	I _{SOURCE}	V _{ID} =15mV to 5V V3 = 3.5V	2			mA


PULSE-WIDTH-MODULATION CONTROL CIRCUITS
AZ494A/C
Electrical Characteristics (Continued)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
PWM Comparator Section						
Input Threshold Voltage	V_{ITH}	Zero duty cycle		4	4.5	V
Input Sink Current	I_{SINK}	$V_3 = 0.7V$	-0.3	-0.7		mA
Output Section						
Output Saturation Voltage	Common Emitter	$V_{CE(SAT)}$ $V_E = 0V, I_C = 200mA$		1.1	1.3	V
	Emitter Follower	$V_{CC(SAT)}$ $V_{CC} = 15V, I_E = -200mA$		1.5	2.5	
Collector Off-State Current	$I_C(OFF)$	$V_{CE} = 36V, V_{CC} = 36V$		2	100	μA
Emitter Off-State Current	$I_E(OFF)$	$V_{CC} = V_C = 36V, V_E = 0$			-100	μA
Total Device						
Supply Current	I_{CC}	Pin 6 = V_{REF} , $V_{CC} = 15V$		6	10	mA
Output Switching Characteristics						
Rise Time	t_R	Common Emitter Common Collector		100	200	ns
Fall Time	t_F	Common Emitter Common Collector		25	100	ns

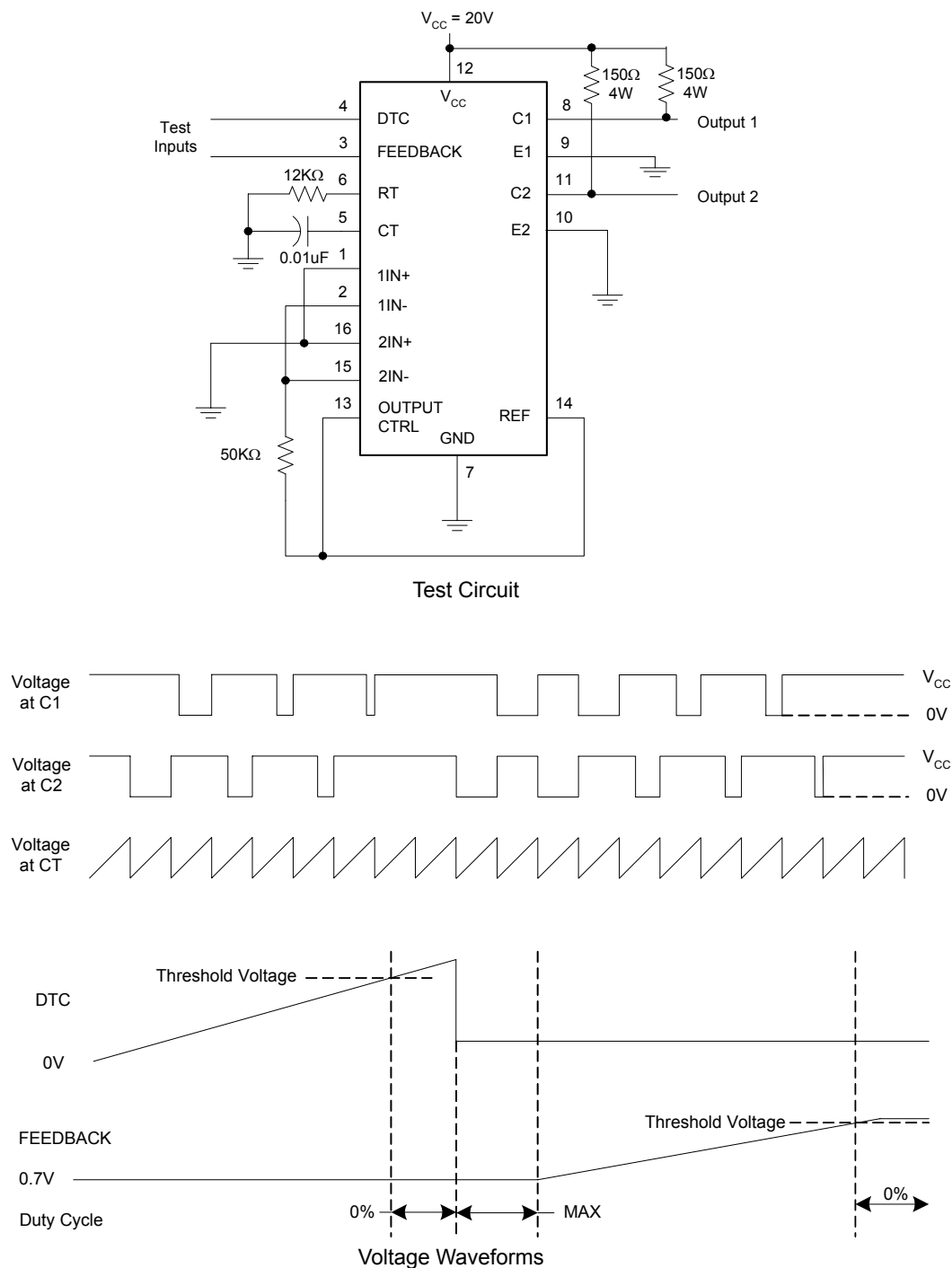
**PULSE-WIDTH-MODULATION CONTROL CIRCUITS****AZ494A/C****Parametr Measurement information**

Figure 4. Operational Test Circuit and Waveforms

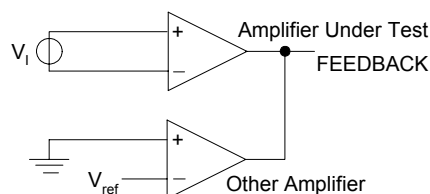
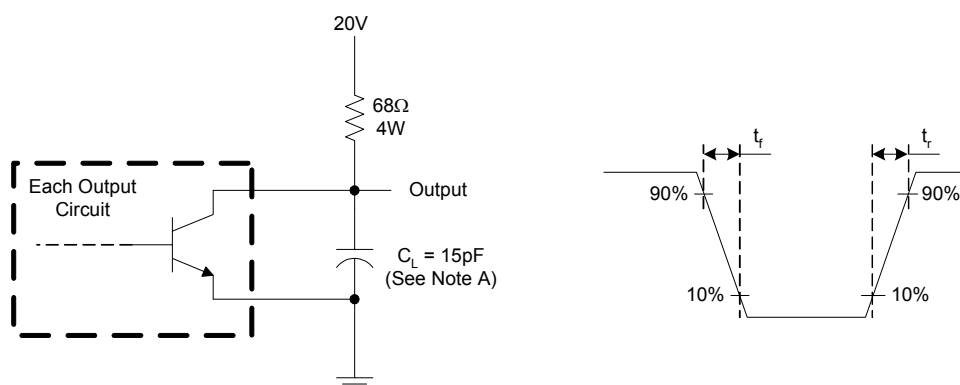
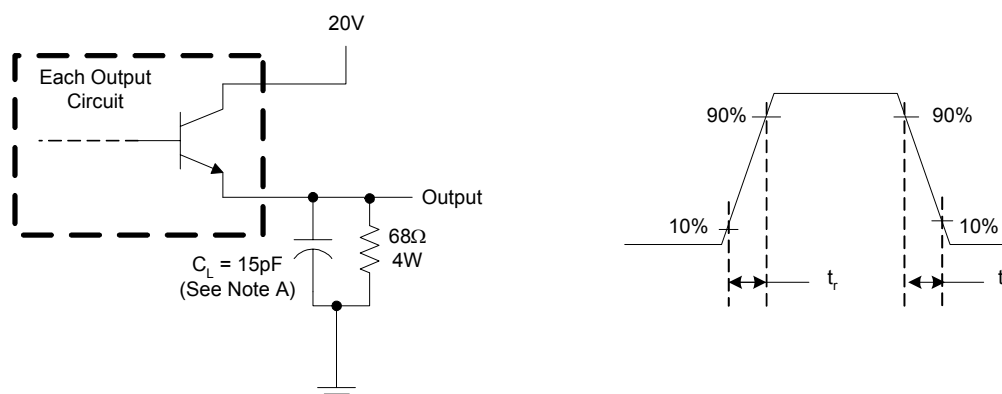
Parametr Measurement information (Continued)


Figure 5. Error Amplifier Characteristics



Note A: C_L includes probe and jig capacitance.

Figure 6. Common-Emitter Configuration



Note A: C_L includes probe and jig capacitance.

Figure 7. Emitter-Follower Configuration

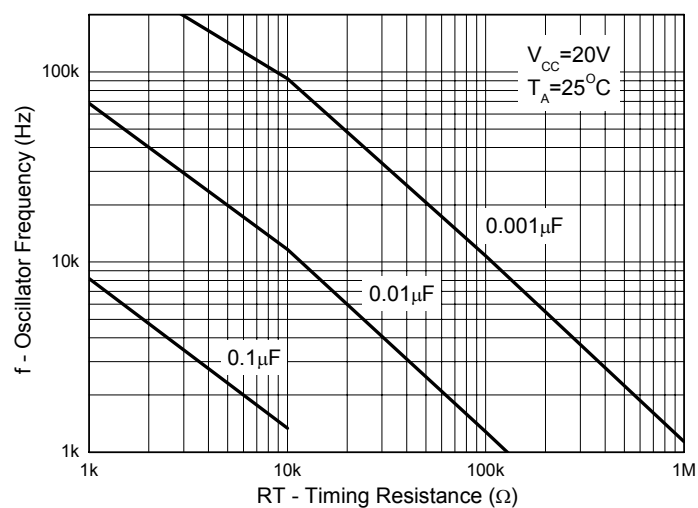
**Typical Performance Characteristics**

Figure 8. Oscillator Frequency vs. RT and CT

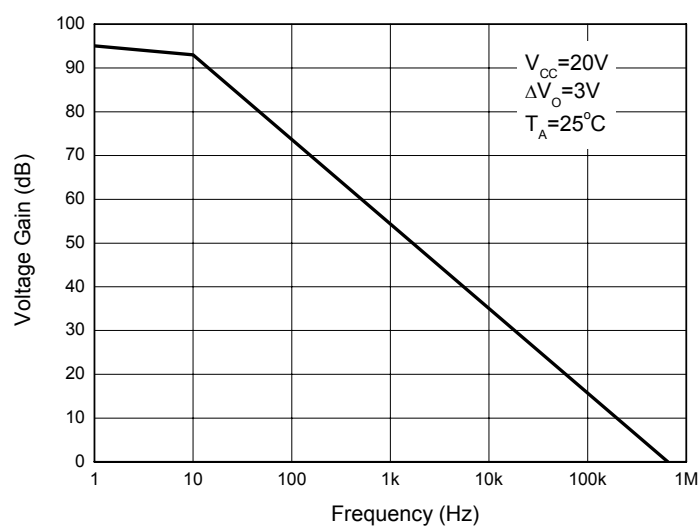


Figure 9. Error Amplifier Small-Signal Voltage Gain vs. Frequency

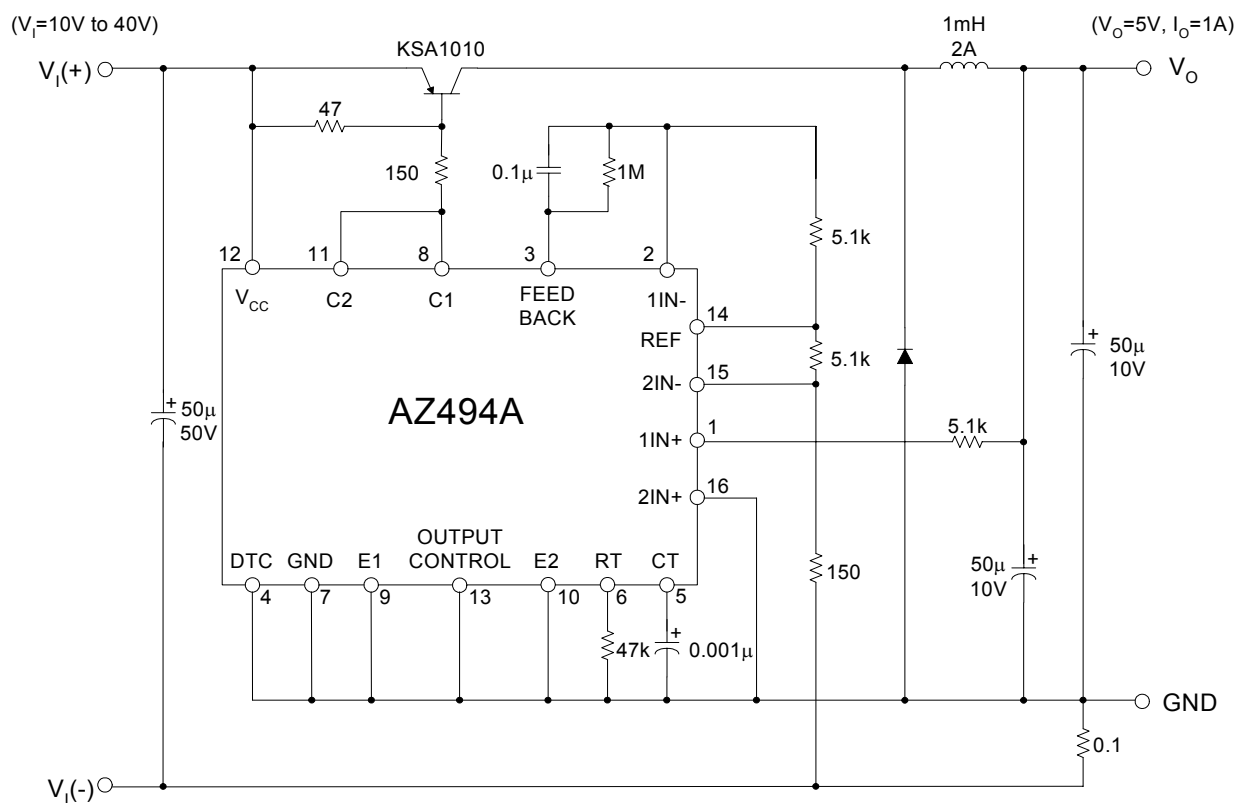
**Typical Applications**

Figure 10. Pulse Width Modulated Step-Down Converter

**AZ494A/C****SOIC-16**

Unit: mm(inch)

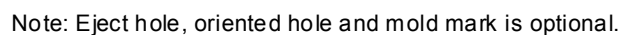


**AZ494A/C**

Mechanical Dimensions (Continued)

DIP-16

Unit: mm(inch)





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